

Product data sheet

1. General description

Planar passivated high commutation three quadrant triac in a TO220F "full pack" plastic package. This triac is intended for use in motor control circuits where very high blocking voltage can occur. Rated junction temperature ($T_{j(max)}$ = 150 °C) without the aid of a snubber. It is used in applications where "high junction operating temperature capability" is required.

2. Features and benefits

- High junction operating temperature capability (T_{i(max)} = 150 °C)
- Full cycle AC conduction
- Over-voltage withstand capability to IEC 61000-4-5
- · Pin compatible with standard triacs
- Planar passivated for voltage ruggedness and reliability
- · Protective self turn-on capability for high energy transients
- Triggering in three quadrants only
- Very high immunity to IEC 61000-4-4 fast transient
- Package meets UL94V0 flammability requirement
- Package is RoHS compliant
- Package meets UL1557 isolation test requirement rated at 2500V RMS

3. Applications

- AC fan, pump and compressor controls
- · Highly inductive, resistive and safety loads
- · Large and small appliances (White Goods)
- · Reversing induction motor controls e.g. vertical axis washing machines
- Applications subject to high temperature (T_{i(max)} = 150 °C)

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _h ≤ 103°C; <u>Fig.1; Fig. 2; Fig. 3</u>	-	-	8	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p =20ms; <u>Fig. 4; Fig. 5</u>	-	-	80	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p =16.7ms	-	-	88	А
Tj	junction temperature		-	-	150	°C
Static ch	aracteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	-	-	35	mA
		V_{D} = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	-	-	35	mA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; <u>Fig. 7</u>	-	-	35	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	40	mA
V _T	on-state voltage	I _T = 10 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.25	1.6	V
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit	200	-	-	V/µs
		V_{DM} = 536 V; T _j = 150 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit	100	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_{DM} = 400 \text{ V}; \text{ T}_{j} = 150 \text{ °C}; \text{ I}_{T(RMS)} = 8 \text{ A}; $ $dV_{com}/dt = 20 \text{ V}/\mu\text{s}; \text{ (snubberless condition); gate open circuit}$	1	-	-	A/ms

5. Pinning information

Table 2. P	Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	T1	main terminal 1	mb	NI				
2	T2	main terminal 2		T2-T1				
3	G	gate		sym051				
mb	n.c.	mounting base; isolated						

6. Ordering information

Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	Name		method	quantity	version	issue date		
BTA208X-800CT	TO220F	BTA208X-800CTQ	Tube	50	SOT186A	14-Nov-2013		

7. Marking

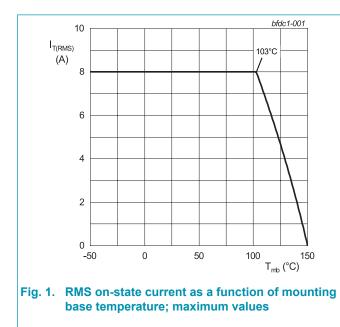
Table 4. Marking codes	
Type number	Marking codes
BTA208X-800CT	BTA208X-800CT

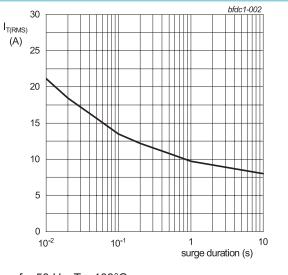
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

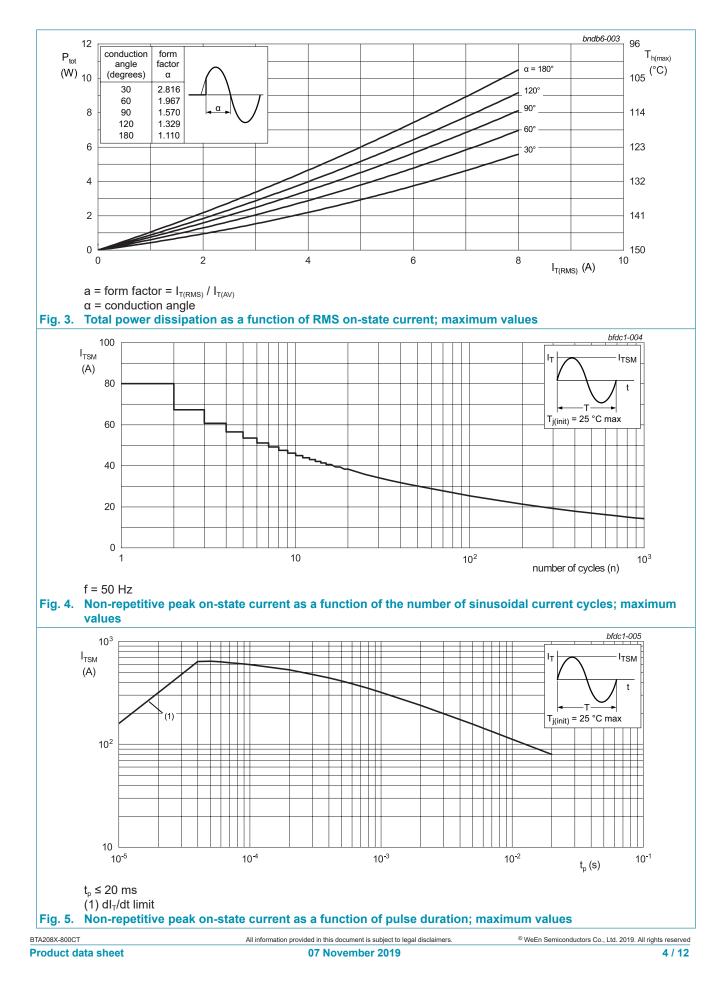
Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 103°C; <u>Fig.1; Fig. 2</u> ; <u>Fig. 3</u>	-	8	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4;</u> <u>Fig. 5</u>	-	80	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	88	А
l ² t	I ² t for fusing	t_P = 10 ms; sine wave pulse	-	30	A ² s
dl _T /dt	rate of rise of on-state current	I _G = 70 mA	-	150	A/µs
I _{GM}	peak gate current		-	2	А
P_{GM}	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C







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9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-h)}}$	thermal resistance from junction to heatsink	full cycle; <u>Fig. 6</u>	-	-	4.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	-	60	-	K/W



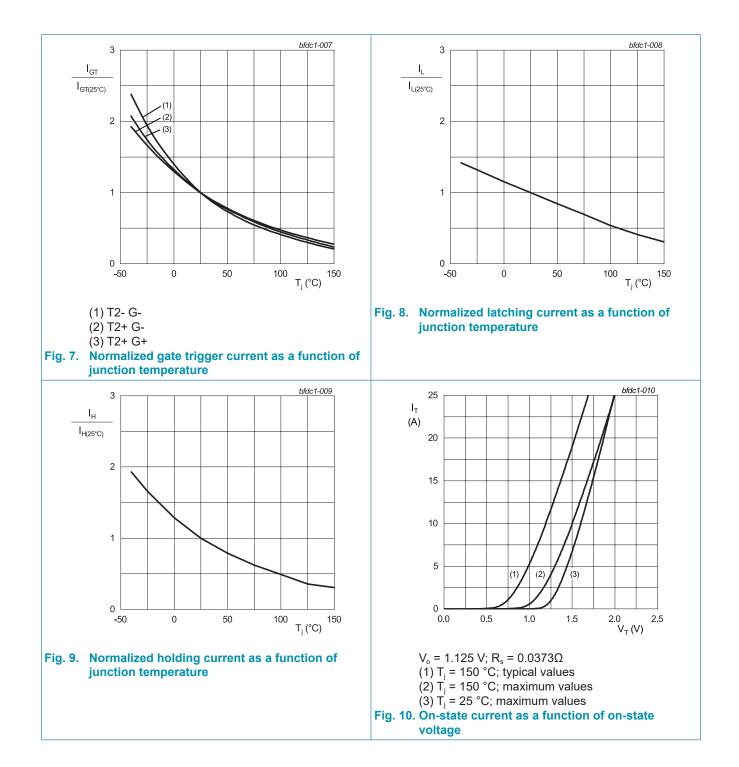
10. Isolation characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{\text{isol}(\text{RMS})}$	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _{mb} = 25 °C	-	-	2500	V
C _{isol}	isolation capacitance	from main terminal 2 to external heatsink; f = 1 MHz; T _{mb} = 25 °C	-	10	-	pF

11. Characteristics

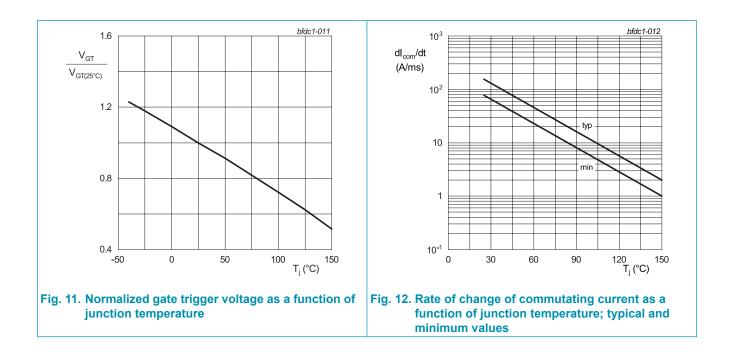
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics			I		
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 7	-	-	35	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 7	-	-	35	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	-	-	35	mA
l	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ } \text{ G+};$ T _j = 25 °C; Fig. 8	-	-	50	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ } \text{ G-};$ T _j = 25 °C; Fig. 8	-	-	70	mA
		V_{D} = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; Fig. 8	-	-	50	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	40	mA
V _T	on-state voltage	I _T = 10A; T _j = 25 °C; <u>Fig. 10</u>	-	1.25	1.6	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A;T _j = 25 °C Fig. 11	-	0.7	1	V
		$V_{\rm D}$ = 400V; $I_{\rm T}$ = 0.1 A; $T_{\rm j}$ = 150 °C	0.25	0.4	-	V
I _D	off-state current	V _D = 800 V; T _j = 25 °C	-	-	10	μA
		V _D = 800 V; T _j = 150 °C	-	0.3	2	mA
Dynamic	characteristics				·	
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536V; T_j = 125 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit	200	-	-	V/µs
		V_{DM} = 536V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	100	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_{DM} = 400 \text{ V}; \text{ T}_{j} = 150 \text{ °C}; \text{I}_{T(RMS)} = 8 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu\text{s}; \text{ (snubberless condition); gate open circuit}$	1	-	-	A/ms
		V_{DM} = 400 V; T _j = 150 °C;I _{T(RMS)} = 8 A; dV _{com} /dt = 10 V/µs; gate open circuit	1.5	-	-	A/ms
		V_{DM} = 400 V; T _j = 150 °C;I _{T(RMS)} = 8 A; dV _{com} /dt = 1 V/µs; gate open circuit	3	-	-	A/ms

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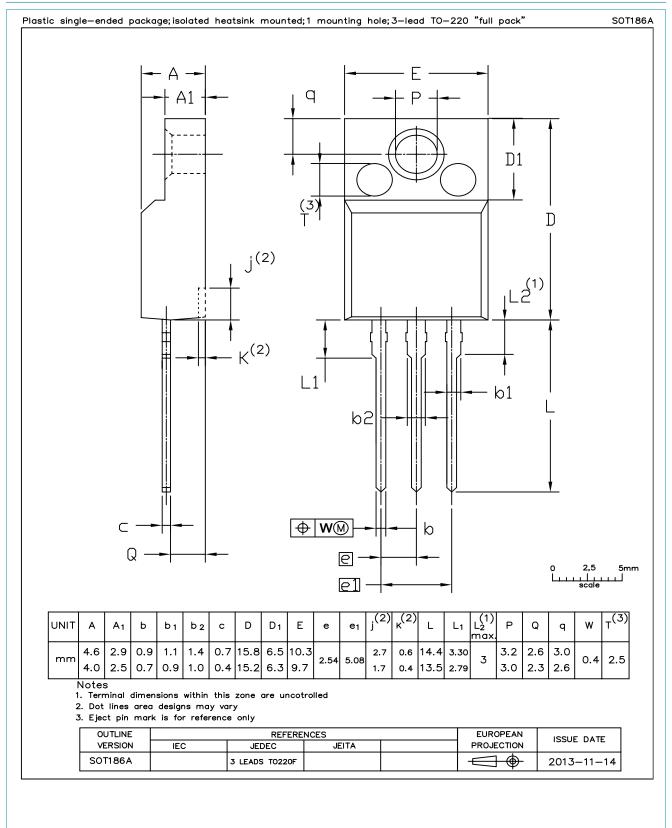


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BTA208X-800CT



12. Package outline



BTA208X-800CT 3Q Hi-Com Triac

13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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